



RIR POWER ELECTRONICS LIMITED

SILICON CONTROLLED RECTIFIERS

High Power Thyristor Hockey Puk Version E-PUK Series 601PE

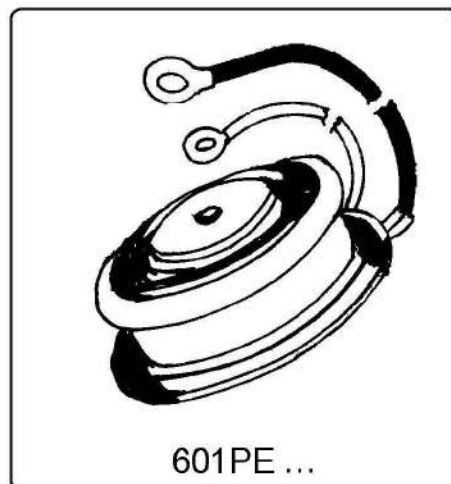
Types : 601PE 150 to 601PE 300

FEATURES

- ❖ Center amplifying gate.
- ❖ International standard case TO-200AB (E-PUK)
- ❖ High profile hockey - puk.

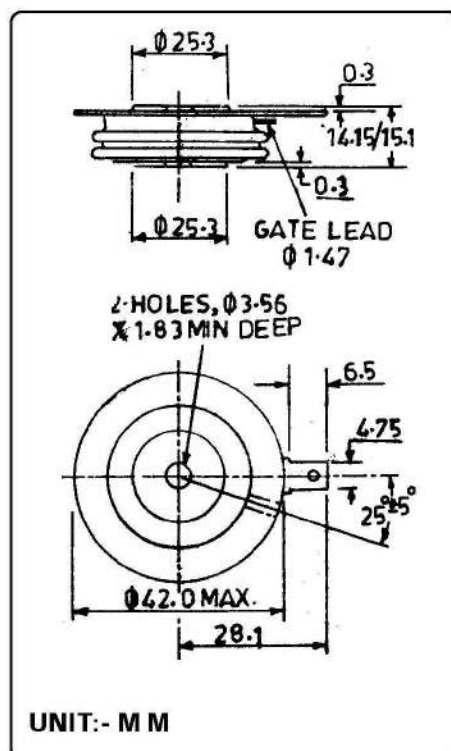
TYPICAL APPLICATIONS

- ❖ DC motor control (e.g. for machine tools).
- ❖ Controlled rectifiers (e.g. for battery charging, UPS).
- ❖ AC controllers (e.g. for temperature control, lights control).



MAJOR RATINGS & CHARACTERISTICS

Parameters	601PE	Units
$I_{T(AV)}$	601	A
@ T_{hs}	55	$^{\circ}\text{C}$
$I_{T(RMS)}$	942	A
@ T_{hs}	55	$^{\circ}\text{C}$
I_{TSM} @ 50 Hz	7500	A
I^2t @ 50 Hz	280	KA^2s
V_{DRM} / V_{RRM}	1500 to 3000	V
t_q typical	250	μs
T_J	-40 to 125	$^{\circ}\text{C}$



SILICON CONTROLLED RECTIFIERS

601PE

ELECTRICAL SPECIFICATION VOLTAGE RATINGS

Type Number	Voltage Code	V_{RRM} / V_{DRM} max. repetitive peak and off-state voltage V	V_{RSM} max. non-repetitive peak voltage V	I_{DRM} / I_{RSM} max. @ 125°C mA
601PE	150	1500	1600	50
	170	1700	1800	
	190	1900	2000	
	210	2100	2200	
	230	2300	2400	
	250	2500	2600	
	270	2700	2800	
	290	2900	3000	
	300	3000	3100	

ON-STATE CONDUCTION

	Parameter	601PE	Units	Conditions
$I_{T(AV)}$	Max. average on-state current @ heat sink temperature	601	A	180° conduction, half sine wave double side cooled
		55	°C	
$I_{T(RMS)}$	Max. RMS on-state current	942	A	@55°C heat sink temperature (double side cooled)
I_{TSM}	Max. peak one cycle non-repetitive surge current	7500		t = 10ms
I^2t	Maximum I^2t for fusing	280		t = 10ms
				Sinusoidal half wave, Initial $T_J = T_J$ max.
V_{TO}	Threshold voltage	1.14	V	$T_J = T_J$ max.
r_L	On state slope resistance	0.78	mΩ	$T_J = T_J$ max.
V_{TM}	Max. on state voltage	2.1	V	$I_{PK} = 1500$ A, $T_J = 125^\circ\text{C}$, $t_p = 10$ ms sine pulse
I_H	Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, anode supply 12V resistive load
I_L	Latching current	1000		

SWITCHING

	Parameter	601PE	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	500	A/μs	Gate drive 20V, 20Ω, $t_r \leq 1$ μs $T_J = 125^\circ\text{C}$, anode voltage $\leq 80\% V_{DRM}$
t_d	Typical delay time	1.0	μs	Gate current 1A, $di/dt = 1$ A/μs $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ\text{C}$
t_q	Typical turn-off time	250		$I_{TM} = 550$ A, $T_J = 125^\circ\text{C}$, $di/dt = 40$ A/μs, $V_R = 50$ V $dv/dt = 20$ V/μs, Gate 0V 100Ω, $t_p = 500$ μs

SILICON CONTROLLED RECTIFIERS

601PE

BLOCKING

	Parameter	601PE	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	1000	V/ μ s	$T_J = 125^\circ\text{C}$, linear to 80% rated V_{DRM}
I_{RRM} I_{DRM}	Max. peak reverse and off-state leakage current	5.0	mA	$T_J = 125^\circ\text{C}$, rated V_{DRM} / V_{RRM} applied

TRIGGERING

	Parameter	601PE		Units	Conditions
P_{GM}	Maximum peak gate power	10.0		W	$T_J = 125^{\circ}\text{C}$, $t_p \leq 5\text{ms}$
$P_{G(AV)}$	Maximum average gate power	2.0			$T_J = 125^{\circ}\text{C}$, $f = 50\text{Hz}$, $d\% = 50$
I_{GM}	Max. peak positive gate current	3.0		A	$T_J = 125^{\circ}\text{C}$, $t_p \leq 5\text{ms}$
$+V_{GM}$	Max. peak positive gate voltage	20		V	$T_J = 125^{\circ}\text{C}$, $t_p \leq 5\text{ms}$
$-V_{GM}$	Max. peak negative gate voltage	5.0			
I_{GT}	DC gate current required to trigger	TYP.	MAX.	mA	$T_J = 25^{\circ}\text{C}$ Max. required gate trigger/current / voltage are the lowest value which will trigger all units 12V anode-to-cathode applied.
		100	200		
V_{GT}	DC gate voltage required to trigger	1.8	3.0	V	$T_J = 25^{\circ}\text{C}$
I_{GD}	DC gate current not to trigger	10		mA	$T_J = 125^{\circ}\text{C}$ Max. gate current / voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied.
V_{GD}	DC gate voltage not to trigger	0.25		V	

THERMAL AND MECHANICAL SPECIFICATION

	Parameter	601PE	Units	Conditions
T_J	Max. operating temperature range	-40 to 125	$^\circ\text{C}$	
T_{stg}	Max. storage temperature range	-40 to 150		
$R_{\text{thJ-HS}}$	Max. thermal resistance, junction to heat sink	0.05	K/W	DC operation double side cooled
F	Mounting force, $\pm 10\%$	9800 (1000)	N (kg)	
wt	Approximate weight	83	g	
	Case style	To - 200AB (E-PUK)		See outline